Old Company Name in Catalogs and Other Documents

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Renesas Electronics website: http://www.renesas.com

April 1st, 2010 Renesas Electronics Corporation

Issued by: Renesas Electronics Corporation (http://www.renesas.com)

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HAF2012(L), HAF2012(S)

Silicon N Channel MOS FET Series Power Switching

REJ03G1139-0400 Rev.4.00 Jul 13, 2007

Description

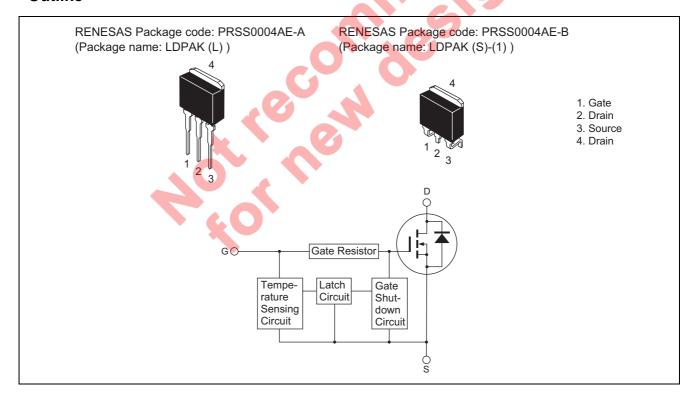
This FET has the over temperature shut-down capability sensing to the junction temperature.

This FET has the built-in over temperature shut-down circuit in the gate area. And this circuit operation to shut-down the gate voltage in case of high junction temperature like applying over power consumption, over current etc.

Features

- Logic level operation (4 to 6 V Gate drive)
- High endurance capability against to the short circuit
- Built-in the over temperature shut-down circuit
- Latch type shut-down operation (Need 0 voltage recovery)

Outline



Absolute Maximum Ratings

 $(Ta = 25^{\circ}C)$

Item	Symbol	Value	Unit
Drain to source voltage	V _{DSS}	60	V
Gate to source voltage	V_{GSS}	16	V
	V_{GSS}	-2.8	V
Drain current	I _D	20	A
Drain peak current	I _{D (pulse)} Note 1	40	A
Body-drain diode reverse drain current	I _{DR}	20	A
Channel dissipation	Pch Note 2	50	W
Channel temperature	Tch	150	°C
Storage temperature	Tstg	−55 to +150	°C

Notes: 1. PW \leq 10 μ s, duty cycle \leq 1%

2. Value at Ta = 25°C

Typical Operation Characteristics

 $(Ta = 25^{\circ}C)$

Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Input voltage	V _{IH}	3.5	_		V	
	V _{IL}	_		1.2	V	
Input current	I _{IH1}	_	1	100	μΑ	$Vi = 8 V, V_{DS} = 0$
(Gate non shut down)	I _{IH2}	_		50	μΑ	$Vi = 3.5 V, V_{DS} = 0$
	I _{IL}		_		μΑ	$Vi = 1.2 V, V_{DS} = 0$
Input current	I _{IH (sd) 1}		0.8	X	mA	$Vi = 8 V, V_{DS} = 0$
(Gate shut down)	I _{IH (sd) 2}	<u> </u>	0.35	—	mA	$Vi = 3.5 V, V_{DS} = 0$
Shut down temperature	Tsd		175		°C	Channel temperature
Gate operation voltage	V _{OP}	3.5		13	V	

Horney

Electrical Characteristics

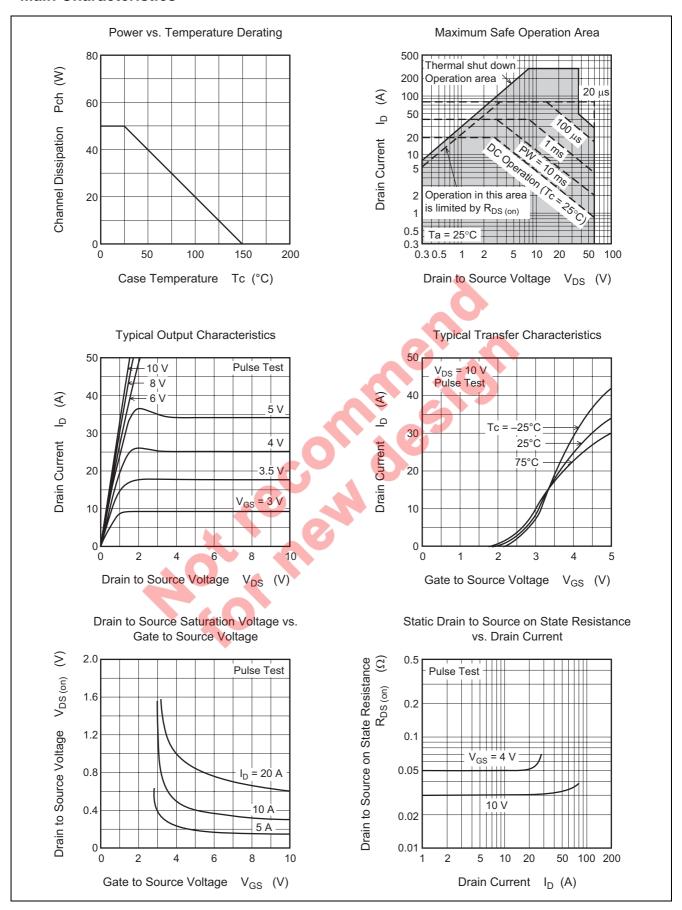
 $(Ta = 25^{\circ}C)$

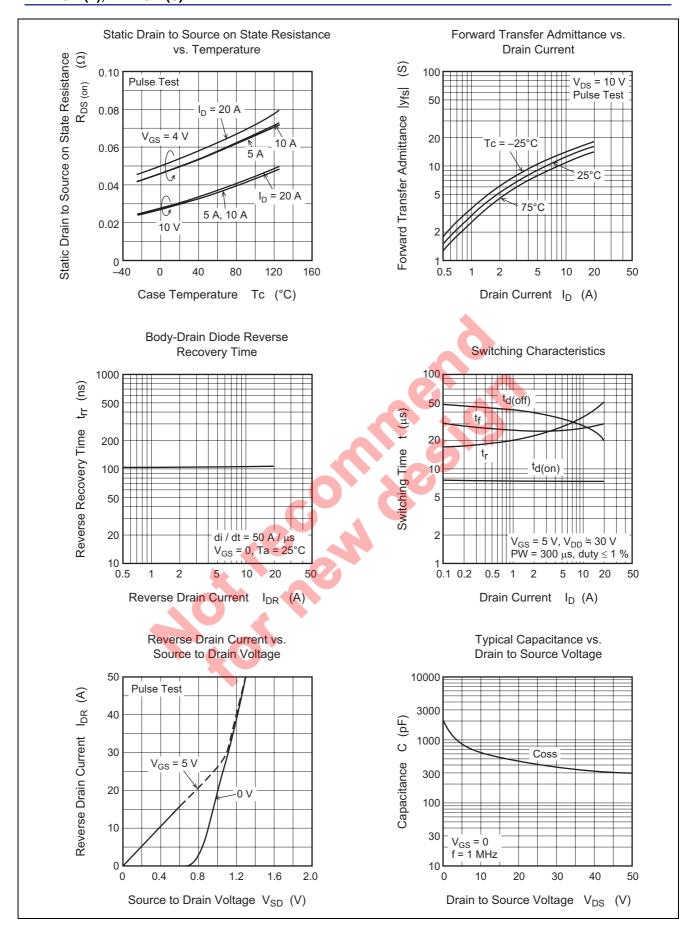
Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Drain current	I _{D1}	10	_	_	Α	$V_{GS} = 3.5 \text{ V}, V_{DS} = 2 \text{ V}$
	I _{D2}	_	_	10	mA	V _{GS} = 1.2 V, V _{DS} = 2 V
Drain to source breakdown voltage	V _{(BR) DSS}	60	_	_	V	$I_D = 10 \text{ mA}, V_{GS} = 0$
Gate to source breakdown voltage	V _(BR) GSS	16	_	_	V	$I_G = 100 \mu A, V_{DS} = 0$
	V _(BR) GSS	-2.8	_		V	$I_G = -100 \ \mu A, \ V_{DS} = 0$
Gate to source leak current	I _{GSS1}	_	_	100	μΑ	$V_{GS} = 8 \text{ V}, V_{DS} = 0$
	I _{GSS2}	_	_	50	μΑ	$V_{GS} = 3.5 \text{ V}, V_{DS} = 0$
	I _{GSS3}	_	_	1	μΑ	$V_{GS} = 1.2 \text{ V}, V_{DS} = 0$
	I_{GSS4}	_	_	-100	μΑ	$V_{GS} = -2.4 \text{ V}, V_{DS} = 0$
Input current (shut down)	I _{GS (op) 1}	_	0.8		mA	$V_{GS} = 8 \text{ V}, V_{DS} = 0$
	I _{GS (op) 2}	_	0.35		mA	$V_{GS} = 3.5 \text{ V}, V_{DS} = 0$
Zero gate voltage drain current	I _{DSS}	_	_	250	μΑ	$V_{DS} = 50 \text{ V}, V_{GS} = 0$
Gate to source cutoff voltage	V _{GS (off)}	1.0	_	2.25	V	$I_D = 1 \text{ mA}, V_{DS} = 10 \text{ V}$
Static drain to source on state resistance	R _{DS (on)}	_	50	65	mΩ	$I_D = 10 \text{ A}, V_{GS} = 4 \text{ V}^{\text{Note 3}}$
	R _{DS (on)}	_	30	43	mΩ	$I_D = 10 \text{ A}, V_{GS} = 10 \text{ V}^{\text{Note 3}}$
Forward transfer admittance	y _{fs}	6	12	d	S	$I_D = 10 \text{ A}, V_{DS} = 10 \text{ V}^{\text{Note 3}}$
Output capacitance	Coss	_	630	>	pF	$V_{DS} = 10 \text{ V}, V_{GS} = 0$
						f = 1 MHz
Turn-on delay time	t _{d (on)}		7.5	+	μs	I _D = 5 A
Rise time	t _r		29	1	μs	$V_{GS} = 5 V$
Turn-off delay time	t _{d (off)}		34		μs	$R_L = 6 \Omega$
Fall time	t _f		26	X-	μs	
Body-drain diode forward voltage	V_{DF}) <u> </u>	1.0	_	V	$I_F = 20 \text{ A}, V_{GS} = 0$
Body-drain diode reverse recovery time	t _{rr}	_	110	_	ns	$I_F = 20 \text{ A}, V_{GS} = 0$
						di _F /dt = 50 A/μs
Over load shut down operation time Note4	t _{os1}	1	1.8	_	ms	$V_{GS} = 5 \text{ V}, V_{DD} = 12 \text{ V}$
	t _{os2}		0.7	_	ms	$V_{GS} = 5 \text{ V}, V_{DD} = 24 \text{ V}$

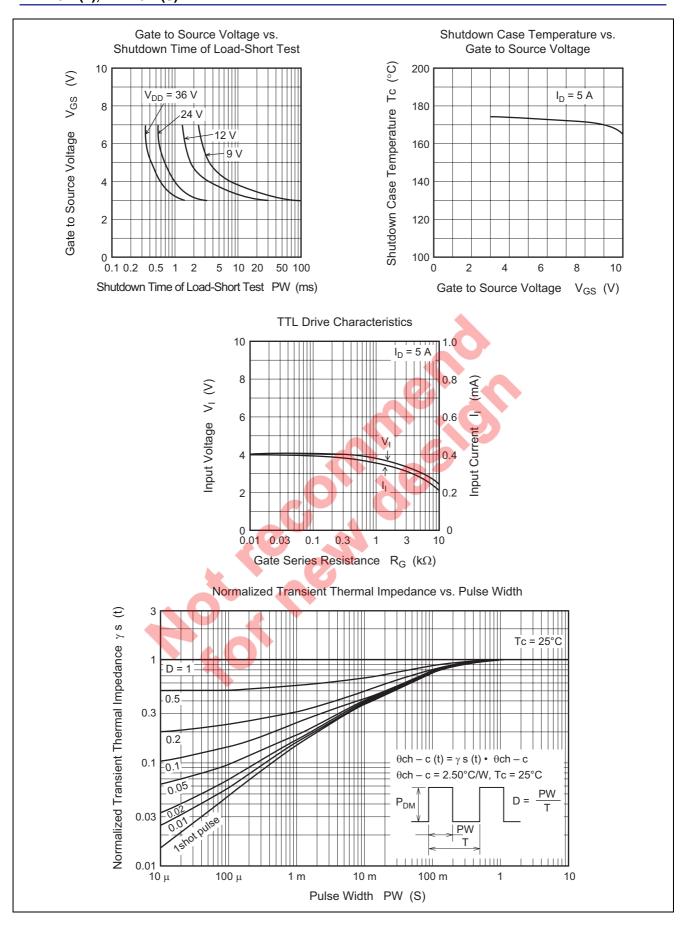
Notes: 3. Pulse test

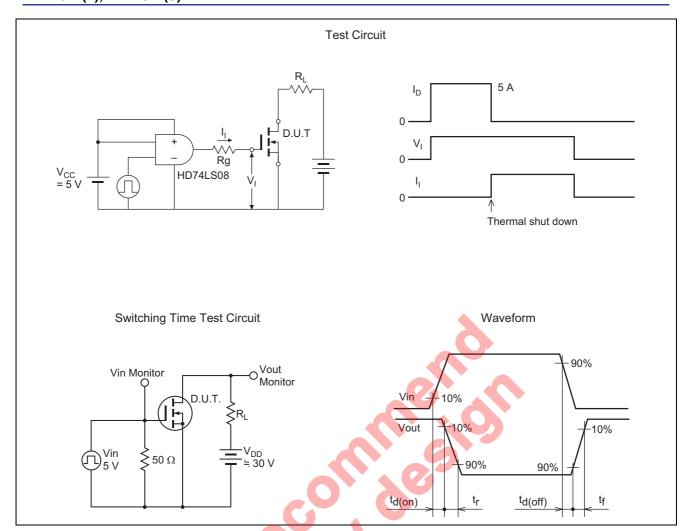
4. Including the junction temperature rise of the over loaded condition.

Main Characteristics

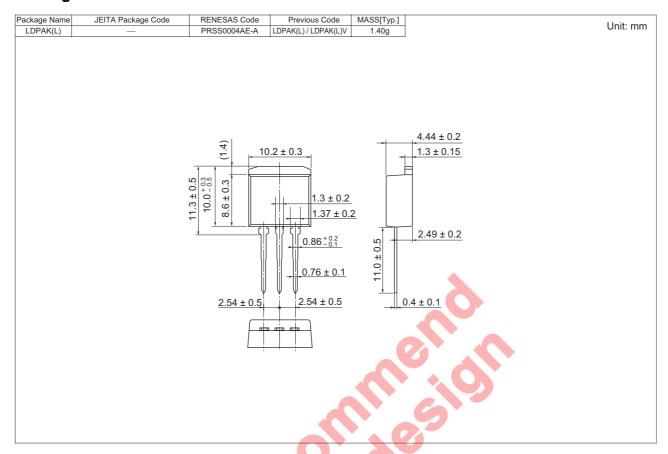


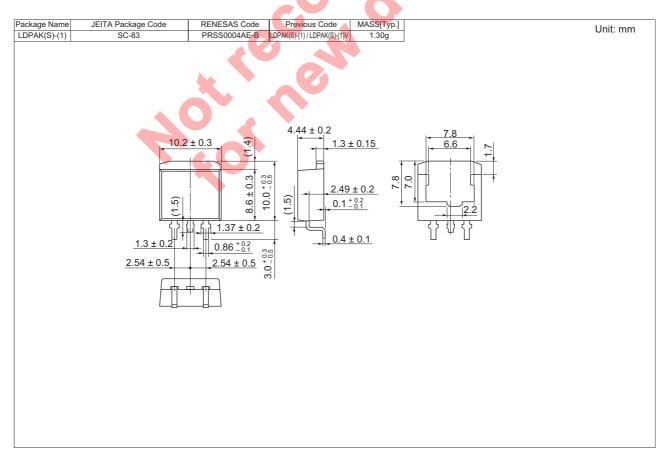






Package Dimensions





Ordering Information

Part Name	Quantity	Shipping Container
HAF2012-90L	Max: 50 pcs/sack	Sack
HAF2012-90S	Max: 50 pcs/sack	Sack
HAF2012-90STL	1000 pcs/Reel	Embossed tape
HAF2012-90STR	1000 pcs/Reel	Embossed tape



Renesas Technology Corp. sales Strategic Planning Div. Nippon Bldg., 2-6-2, Ohte-machi, Chiyoda-ku, Tokyo 100-0004, Japan

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Renesas Technology America, Inc

450 Holger Way, San Jose, CA 95134-1368, U.S.A Tel: <1> (408) 382-7500, Fax: <1> (408) 382-7501

Renesas Technology Europe Limited
Dukes Meadow, Millboard Road, Bourne End, Buckinghamshire, SL8 5FH, U.K.
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Renesas Technology (Shanghai) Co., Ltd.
Unit 204, 205, AZIACenter, No.1233 Lujiazui Ring Rd, Pudong District, Shanghai, China 200120 Tel: <86> (21) 5877-1818, Fax: <86> (21) 6887-7898

Renesas Technology Hong Kong Ltd.
7th Floor, North Tower, World Finance Centre, Harbour City, 1 Canton Road, Tsimshatsui, Kowloon, Hong Kong Tel: <852> 2265-6688, Fax: <852> 2730-6071

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Renesas Technology Korea Co., Ltd. Kukje Center Bldg. 18th Fl., 191, 2-ka, Hangang-ro, Yongsan-ku, Seoul 140-702, Korea Tel: <82> (2) 796-3115, Fax: <82> (2) 796-2145

Renesas Technology Malaysia Sdn. Bhd
Unit 906, Block B, Menara Amcorp, Amcorp Trade Centre, No.18, Jalan Persiaran Barat, 46050 Petaling Jaya, Selangor Darul Ehsan, Malaysia Tel: <603> 7955-9390, Fax: <603> 7955-9510